

isc Silicon NPN Power Transistor

2SC4960

DESCRIPTION

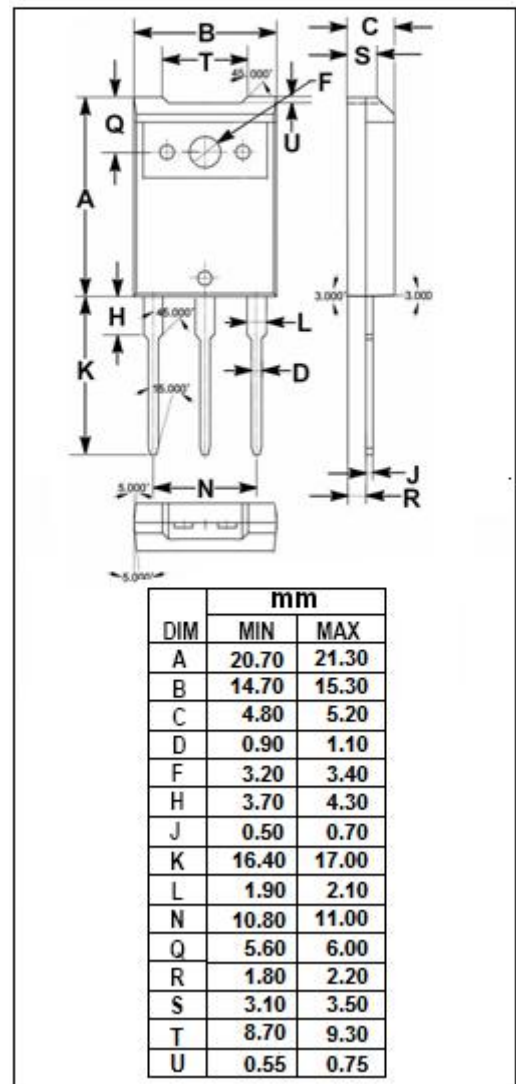
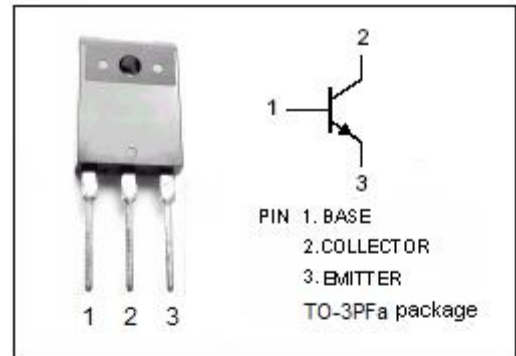
- High Collector-Base Breakdown Voltage-
: $V_{(BR)CBO} = 900V(\text{Min})$
- High Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for power switching applications.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	900	V
V_{CES}	Collector-Emitter Voltage	900	V
V_{CEO}	Collector-Emitter Voltage	800	V
V_{EBO}	Emitter-Base voltage	7	V
I_C	Collector Current-Continuous	1	A
I_{CM}	Collector Current-Peak	2	A
I_B	Base Current-Continuous	0.3	A
P_C	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	40	W
	Collector Power Dissipation @ $T_a=25^\circ\text{C}$	3	
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA; I _B = 0	800			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.2A; I _B = 40mA			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.2A; I _B = 40mA			1.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 900V; I _E = 0			50	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			50	μ A
h _{FE-1}	DC Current Gain	I _C = 50mA; V _{CE} = 5V	6			
h _{FE-2}	DC Current Gain	I _C = 0.5A; V _{CE} = 5V	3			
f _T	Current-Gain—Bandwidth Product	I _C = 50mA; V _{CE} = 10V; f= 1MHz		4		MHz

Switching times

t _{on}	Turn-On Time	I _C = 0.2A; I _{B1} = 40mA, I _{B2} = -80mA; V _{CC} = 250V			1.0	μ s
t _{stg}	Storage Time				3.0	μ s
t _f	Fall Time				1.0	μ s

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